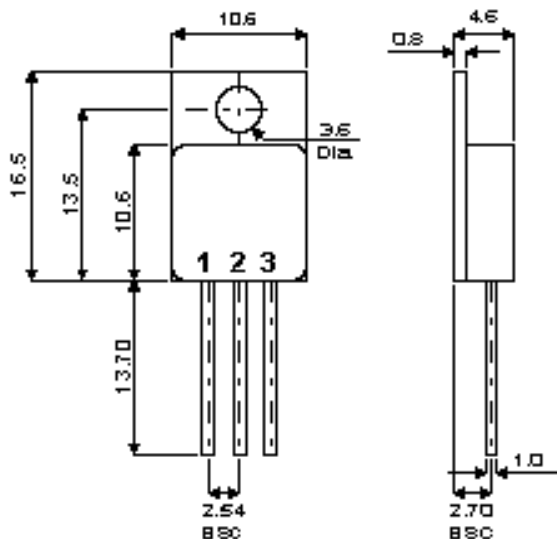


**MECHANICAL DATA**

Dimensions in mm



**TO220 METAL PACKAGE**

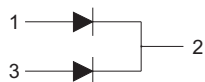
**DUAL SCHOTTKY  
BARRIER DIODE IN  
TO220 METAL PACKAGE  
FOR HI-REL APPLICATIONS**

**FEATURES**

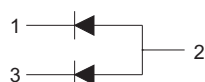
- HERMETIC TO220 METAL PACKAGE
- ISOLATED CASE
- SCREENING OPTIONS AVAILABLE
- OUTPUT CURRENT 16A
- LOW  $V_F$
- LOW LEAKAGE

**ELECTRICAL CONNECTIONS**

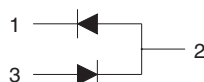
**Common Cathode**    **Common Anode**    **Series Connection**  
SB16-100M            SB16-100AM            SB16-100RM



1 = A<sub>1</sub> Anode 1  
2 = K Cathode  
3 = A<sub>2</sub> Anode 2



1 = K<sub>1</sub> Cathode 1  
2 = A Anode  
3 = K<sub>2</sub> Cathode 2



1 = K<sub>1</sub> Cathode 1  
2 = Centre Tap  
3 = A<sub>2</sub> Anode

<b>ABSOLUTE MAXIMUM RATINGS</b> ( $T_{case} = 25^{\circ}C$ unless otherwise stated)		SB16-100M SB16-100AM SB16-100RM
$V_{RRM}$	Peak Repetitive Reverse Voltage	100V
$V_{RSM}$	Peak Non-Repetitive Reverse Voltage	100V
$V_R$	Continuous Reverse Voltage	100V
$I_O$	Output Current	16A
$I_{FSM}$	Peak Non-Repetitive Surge Current (50Hz)	245A
$T_{STG}$	Storage Temperature Range	-55°C to 150°C
$T_J$	Maximum Operating Junction Temperature	150°C

**ELECTRICAL CHARACTERISTICS** (Per Diode,  $T_{CASE} = 25^{\circ}C$  unless otherwise stated)

Parameter	Test Conditions	Min.	Typ.	Max.	Unit
$V_F$ Forward Voltage	$I_F = 8A$ $T_J = 150^{\circ}C$			0.8	V
	$I_F = 16A$ $T_J = 25^{\circ}C$			1.0	
$I_R$ Reverse Current	$V_R = V_{RRM}$ $T_J = 150^{\circ}C$			30	mA
	$V_R = V_{RRM}$ $T_J = 25^{\circ}C$			500	$\mu A$
$C_d$ Junction Capacitance	$V_R = 5 V$ $f = 1 MHz$		500		pF

Pulse test  $t_p=300\mu s$        $\delta \leq 2\%$

Parameter		Max	Unit
$R_{TH(j-c)}$	Maximum Thermal Resistance Junction To Case	both diodes 1.4	$^{\circ}C/W$
$R_{TH(j-c)}$	Maximum Thermal Resistance Junction To Case	per diode 2.3	$^{\circ}C/W$